

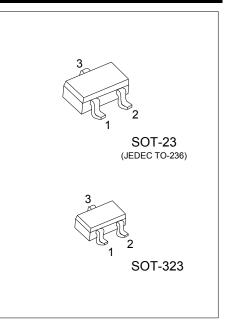
MMBT4403-Q

PNP SILICON TRANSISTOR

PNP GENERAL PURPOSE AMPLIFIER

DESCRIPTION

The UTC **MMBT4403-Q** is designed for use as a general purpose amplifier and switch requiring collector currents up to 500mA.



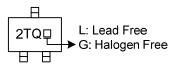
ORDERING INFORMATION

Ordering Number		Deekege	Pin Assignmen		nent	Docking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
MMBT4403L-Q-AE3-R MMBT4403G-Q-AE3-R		SOT-23	В	Е	С	Tape Reel	
MMBT4403L-Q-AL3-R	MMBT4403G-Q-AL3-R	SOT-323	В	E	С	Tape Reel	
Note: Pin Assignment: B: Base F: Emitter C: Collector							

note.	Pin Assignment. B. base	E. Emiller	C. Collector	

MMBT4403G-Q-AE3-R	
(1)Packing Type	(1) R: Tape Reel
(2)Package Type	(2) AE3: SOT-23, AL3: SOT-323
(3)Green Package	(3) G: Halogen Free and Lead Free, L: Lead Free

MARKING



■ ABSOLUTE MAXIMUM RATINGS (T_A=25°C, unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
Collector-Base Voltage	V _{CBO}	-40	V
Collector-Emitter Voltage	V _{CEO}	-40	V
Emitter-Base Voltage	V _{EBO}	-5	V
Collector Current-Continuous	I _C	-600	mA
Total Device Dissipation	P	350	mW
Derate above 25°C	Pc	2.8	mW/°C
Junction Temperature	TJ	+150	°C
Storage Temperature	T _{STG}	-55 ~ +150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

■ THERMAL DATA (T_A=25°C, unless otherwise specified)

CHARACTERISTIC	SYMBOL	RATINGS	UNIT
Junction to Ambient	θ _{JA}	357	°C /W

■ ELECTRICAL CHARACTERISTICS (T_A=25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
OFF CHARACTERISTICS							
Collector-Emitter Breakdown Voltage (Note)	BV _{CEO}	I _C =-1mA, I _B =0	-40			V	
Collector-Base Breakdown Voltage	BV_{CBO}	I _C =-0.1mA, I _E =0	-40			V	
Emitter-Base Breakdown Voltage	BV_{EBO}	I _E =-0.1mA, I _C =0	-5			V	
Collector-Base Cutoff Current	I _{CBO}	V _{CE} =-40V, I _E =0			-0.1	μA	
Collector-Emitter Cutoff Current	I _{CEO}	V _{CE} =-40V, I _B =0			-0.1	μA	
Emitter-Base Cutoff Current	I _{EBO}	V _{EB} =-5V, I _C =0			-0.1	μA	
ON CHARACTERISTICS*			_				
	h_{FE1}	V _{CE} =-1V,I _C =-0.1mA	30				
DC Current Gain	h _{FE2}	V _{CE} =-1V,I _C =-1mA	60				
	h _{FE3}	V _{CE} =-1V,I _C =-10mA	100				
	h _{FE4}	V _{CE} =-2V, I _C =-150mA (Note)	100		300		
	h _{FE5}	V _{CE} =-2V, I _C =-500mA (Note)	20				
Collector Emitter Seturation Voltage	V _{CE(SAT1)}	I _C =-150mA, I _B =-15mA			-0.4	V	
Collector-Emitter Saturation Voltage	V _{CE(SAT2})	I _C =-500mA, I _B =-50mA			-0.75	V	
Base-Emitter Saturation Voltage	V _{BE(SAT1)}	I _C =-150mA, I _B =-15mA(Note)	-0.75		-0.95	V	
	V _{BE(SAT2})	I _C =-500mA, I _B =-50mA			-1.3	V	
SWITCHING CHARACTERISTICS							
Delay Time	t _D	V _{CC} =30V,I _C =150mA,			15	ns	
Rise Time	t _R	V _{BE(OFF)} =-0.5V, I _{B1} =15mA			20	ns	
Storage Time	ts	V _{CC} =30V, I _C =150mA,			225	ns	
Fall Time	t _F	I _{B1} =I _{B2} =15mA			30	ns	

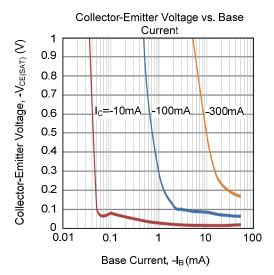
Note: Pulse test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.

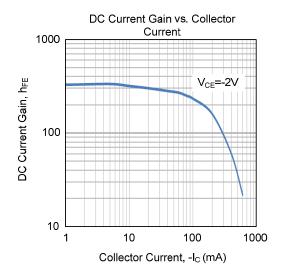


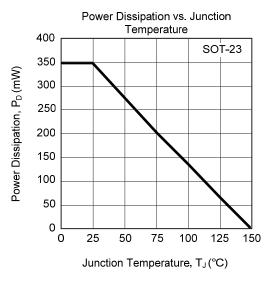
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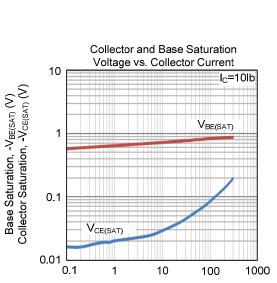
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TYPICAL CHARACTERISTICS

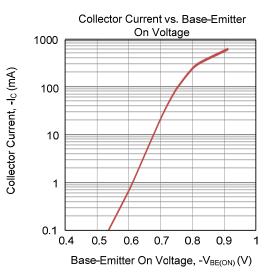








Collector Current, -I_C (mA)





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